MAGX-002735-040L00





GaN HEMT Pulsed Power Transistor 2.7 - 3.5 GHz, 40W Peak, 300us Pulse, 10% Duty Cycle

Production V1 26 March 12

Features

- GaN depletion mode HEMT microwave transistor
- Common source configuration
- Broadband Class AB operation
- Thermally enhanced Cu/Mo/Cu package
- **RoHS Compliant**
- +50V Typical Operation
- MTTF of 600 years (Channel Temperature < 200°C)

Application

Civilian and Military Pulsed Radar



Product Description

The MAGX-002735-040L00 is a gold metalized matched Gallium Nitride (GaN) on Silicon Carbide RF power transistor optimized for civilian and military radar pulsed applications between 2700 - 3500 MHz. Using state of the art wafer fabrication processes, these high performance transistors provide high gain, efficiency, bandwidth, ruggedness over a wide bandwidth for today's demanding application needs. The MAGX-002735-040L00 is constructed using a thermally enhanced Cu/Mo/Cu flanged ceramic package which provides excellent thermal performance. High breakdown voltages allow for reliable and stable operation in extreme mismatched load conditions unparalleled with older semiconductor technologies.

Typical RF Performance

Freq (MHz)	Pin (W Peak)	Pout (W Peak)	Gain (dB)	Id-Pk (A)	Eff (%)
2700	4	44	10.4	1.7	53
2800	4	45	10.5	1.7	53
2900	4	44	10.5	1.6	56
3000	4	43	10.3	1.7	51
3100	4	46	10.6	1.7	54
3200	4	47	10.7	1.7	54
3300	4	47	10.7	1.7	57
3400	4	43	10.3	1.5	55
3500	4	42	10.2	1.5	55

Typical RF performance measured in M/A-COM RF test fixture. Devices tested in common source Class-AB configuration as follows: Vdd=50V, Idq=250mA (pulsed), F=2.7-3.5 GHz, Pulse=300us, Duty=10%.

Ordering Information

able. Commitment to produce in volume is

40W GaN Power Transistor MAGX-002735-040L00 MAGX-002735-SB0PPR **Evaluation Fixture**

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Absolute Maximum Ratings Table (1, 2, 3)

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Supply Voltage (Vdd)	+65V			
Supply Voltage (Vgg)	-8 to 0V			
Supply Current (ld1)	3 A			
Input Power (Pin)	+36 dBm			
Absolute Max. Junction/Channel Temp	200 °C			
Continuous Power Dissipation (Pdiss) at 85 °C	27 W			
Pulsed Power Dissipation (Pavg) at 85 °C	55 W			
MTTF (T _J <200°C)	600 years			
Thermal Resistance, (Tchannel = 200 °C) Pulsed 500uS, 10% Duty cycle	2.0 °C/W			
Operating Temp	-40 to +95C			
Storage Temp	-65 to +150C			
Mounting Temperature	See solder reflow profile			
ESD Min Machine Model (MM)	50 V			
ESD Min Human Body Model (HBM)	>250 V			
MSL Level	MSL1			

⁽¹⁾ Operation of this device above any one of these parameters may cause permanent damage.

⁽³⁾ For saturated performance it recommended that the sum of (3*Vdd + abs(Vgg)) <175

Parameter	Test Conditions	Symbol	Min	Тур	Max	Units
DC CHARACTERISTICS						
Drain-Source Leakage Current	V _{GS} = -8V, V _{DS} = 175V	I _{DS}	-	-	2.5	mA
Gate Threshold Voltage	$V_{DS} = 5V$, $I_D = 6mA$	V _{GS (th)}	-5	-3	-2	V
Forward Transconductance	$V_{DS} = 5V, I_{D} = 1.5mA$	G_{M}	1.0	-	-	S
DYNAMIC CHARACTERISTICS						
Input Capacitance	$V_{DS} = 0v$, $V_{GS} = -8V$, $F = 1MHz$	C _{ISS}	-	13.2	1	pF
Output Capacitance	$V_{DS} = 50V, \ V_{GS} = -8V, F = 1MHz$	Coss	-	5.6	-	pF
Reverse Transfer Capacitance	$V_{DS} = 50V, V_{GS} = -8V, F = 1MHz$	C _{RSS}	-	0.5	-	pF

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⁽²⁾ Channel temperature directly affects a device's MTTF. Channel temperature should be kept as low as possible to maximize lifetime.

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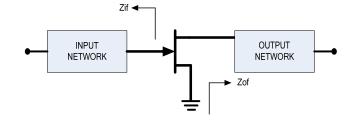
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Electrical Specifications: T_C = 25 ± 5°C (Room Ambient)

Parameter	Test Conditions	Symbol	Min	Тур	Max	Units
Output Power	Pin = 4W Peak	P _{OUT}	36 3.6	44 4.4	-	W Peak W Ave
Power Gain	Pin = 4W Peak	G _P	9.5	10.5	-	dB
Drain Efficiency	Pin = 4W Peak	$\eta_{ extsf{D}}$	48	55	-	%
Load Mismatch Stability	Pin = 4W Peak	VSWR-S	5:1	-	-	-
Load Mismatch Tolerance	Pin = 4W Peak	VSWR-T	10:1	i	-	-

Test Fixture Impedance

F (MHz)	Z _{IF} (Ω)	Z _{OF} (Ω)		
2700	9.2+ j2.1	7.5 + j8.9		
2800	9.0 + j1.5	7.9 + j8.9		
2900	8.7 + j0.8	8.2 + j8.5		
3000	8.3 + j0.1	8.3 + j8.3		
3100	7.8 - j0.7	8.2 + j8.4		
3200	7.0 - j1.5	9.1 + j8.3		
3300	6.0 - j2.0	9.4 + j7.2		
3400	4.9 - j2.1	9.4 + j7.2		
3500	4.2 - j2.7	9.0 + j6.8		



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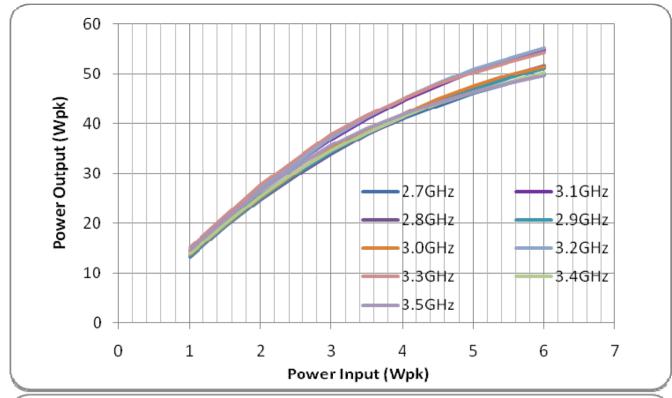
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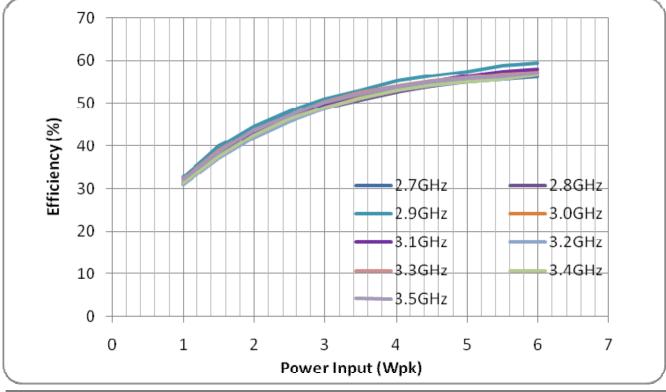
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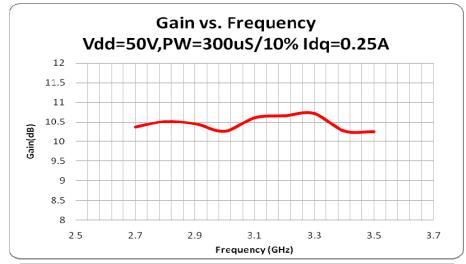
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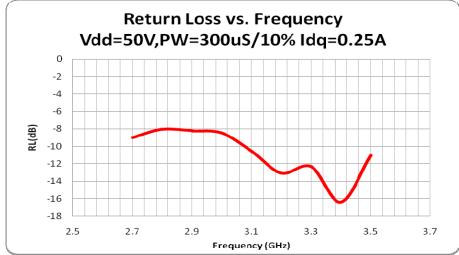
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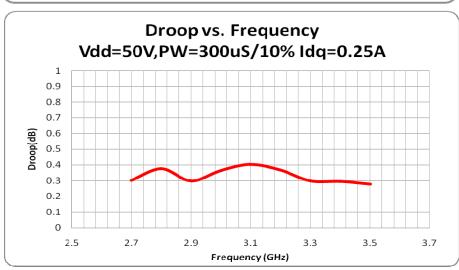
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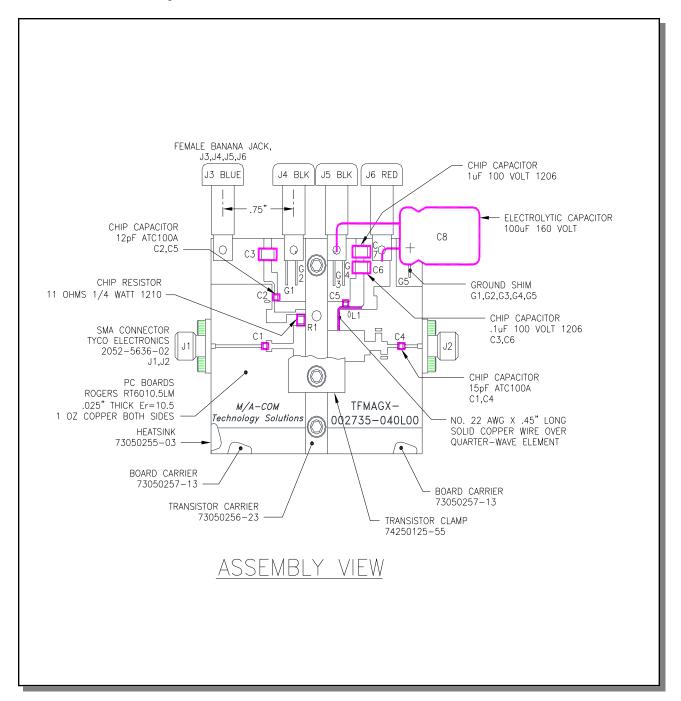
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Test Fixture Assembly



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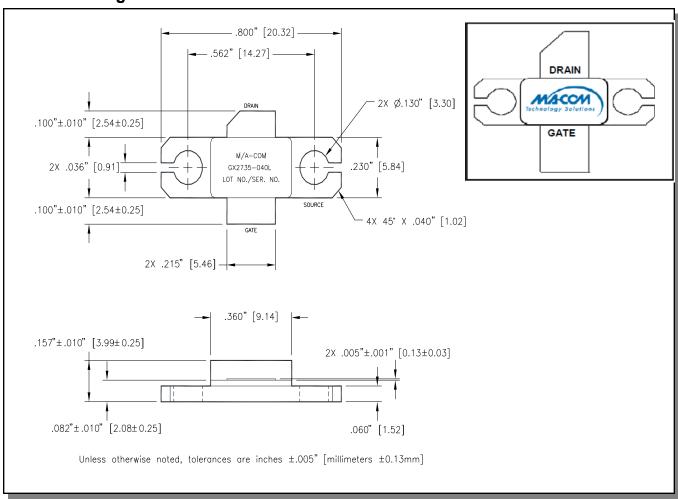
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Outline Drawings



CORRECT DEVICE SEQUENCING

TURNING THE DEVICE ON

- 1. Set V_{GS} to the pinch-off (V_P) , typically -5V
- 2. Turn on V_{DS} to nominal voltage (50V)
- 3. Increase V_{GS} until the I_{DS} current is reached
- 4. Apply RF power to desired level

TURNING THE DEVICE OFF

- 1. Turn the RF power off
- 2. Decrease V_{GS} down to V_P
- 3. Decrease V_{DS} down to 0V
- 4. Turn off V_{GS}

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